

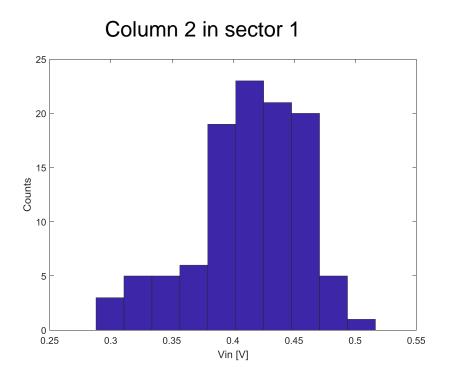
TaichuPix-2 test results

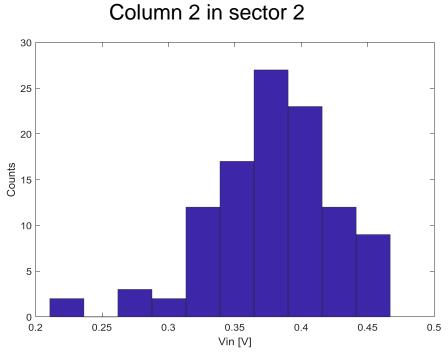
Ying ZHANG

CEP

Pixel analog threshold

 S-curve scanning for one double column, with one pixel enable every time

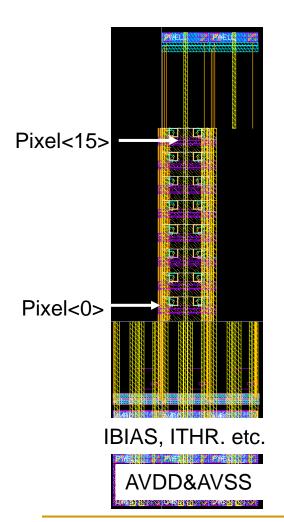




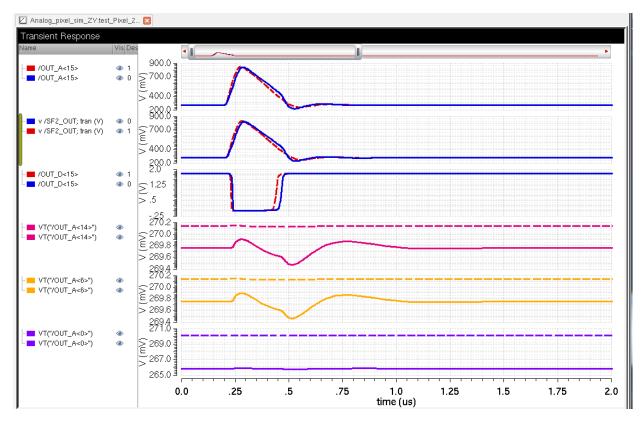
Effect of IR-Drop on power



2x8 pixels (include only analog part) modeled with power & bias bus routed as in TC2



Simulation with schematic and caliber -RCC view for pixel<15>



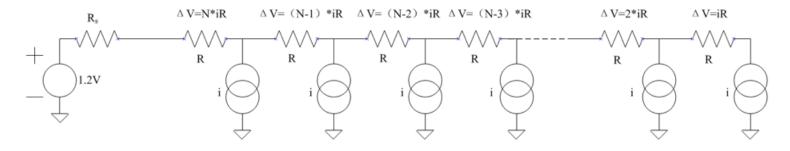
Results show slight difference, no IR-drop effect observed

Effect of IR-Drop on power



IR-drop evaluation, assuming

- > Each pixel consumes same current
- R is the parasitic resistance, from one pixel to the next one along the power line



- The largest IR Drop: $\Sigma_{\Delta V} = (1+2+\cdots N)*iR$ =N(N+1)*iR/2
- Extract the point-to-point parasitic resistance on the layout by PEX
 R_{avdd}= 3.4 ohm/pixel; R_{avss}= 2.8 ohm/pixel;
- $\rightarrow \Delta V \text{max} = 23 \text{ mV}$



Effect of IR-Drop on power

Simulation with one pixel, AVDD = 1.8 V & 1.77 V

